

# NB7L1008M

## 2.5V / 3.3V 1:8 CML Fanout

### Multi-Level Inputs w/ Internal Termination

#### Description

The NB7L1008M is a high performance differential 1:8 Clock/Data fanout buffer. The NB7L1008M produces eight identical output copies of Clock or Data operating up to 6 GHz or 10.7 Gb/s, respectively. As such, the NB7L1008M is ideal for SONET, GigE, Fiber Channel, Backplane and other Clock/Data distribution applications. The differential inputs incorporate internal 50  $\Omega$  termination resistors that are accessed through the VT pin. This feature allows the NB7L1008M to accept various logic standards, such as LVPECL, CML, LVDS, LVCMOS or LVTTL logic levels. The  $V_{REFAC}$  reference output can be used to rebias capacitor-coupled differential or single-ended input signals. The 1:8 fanout design was optimized for low output skew applications. The NB7L1008M is a member of the GigaComm™ family of high performance clock products.

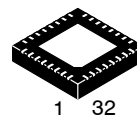
#### Features

- Input Data Rate > 12 Gb/s Typical
- Data Dependent Jitter < 20 ps
- Maximum Input Clock Frequency > 8 GHz Typical
- Random Clock Jitter < 0.8 ps RMS
- Low Skew 1:8 CML Outputs, < 25 ps max
- Multi-Level Inputs, accepts LVPECL, CML, LVDS
- 160 ps Typical Propagation Delay
- 45 ps Typical Rise and Fall Times
- Differential CML Outputs, 400 mV Peak-to-Peak, Typical
- Operating Range:  $V_{CC} = 2.375$  V to 3.6 V, GND = 0 V
- Internal Input Termination Resistors, 50  $\Omega$
- $V_{REFAC}$  Reference Output
- QFN-32 Package, 5 mm x 5 mm
- -40°C to +85°C Ambient Operating Temperature
- These are Pb-Free Devices



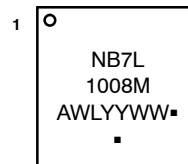
ON Semiconductor®

<http://onsemi.com>



**QFN32**  
**MN SUFFIX**  
**CASE 488AM**

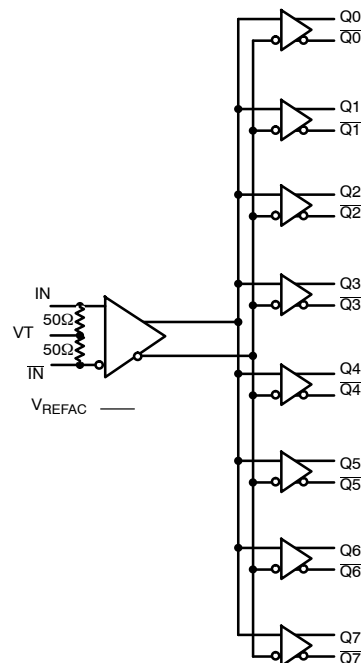
#### MARKING DIAGRAM



- A = Assembly Location
- WL = Wafer Lot
- YY = Year
- WW = Work Week
- = Pb-Free Package

(Note: Microdot may be in either location)

#### SIMPLIFIED LOGIC DIAGRAM



#### ORDERING INFORMATION

See detailed ordering and shipping information on page 9 of this data sheet.

# NB7L1008M

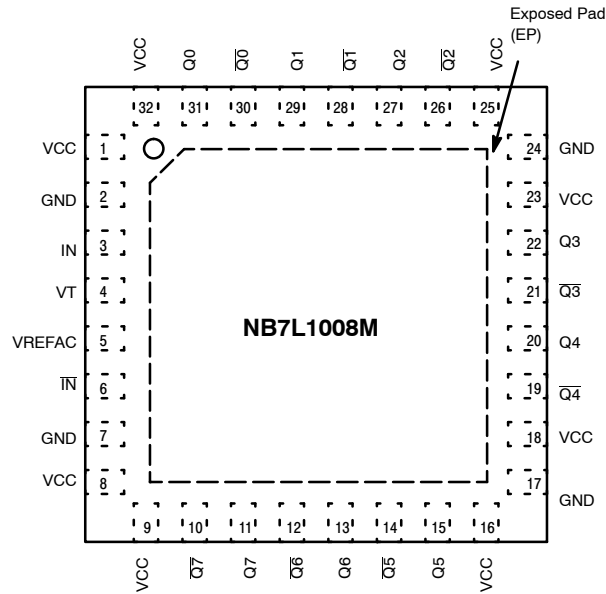


Figure 1. 32-Lead QFN Pinout (Top View)

Table 1. PIN DESCRIPTION

Pin	Name	I/O	Description
3, 6	IN, $\overline{\text{IN}}$	LVPECL, CML, LVDS Input	Non-inverted / Inverted Differential Clock/Data Input. Note 1
4	VT		Internal 50 $\Omega$ Termination Pin for IN and $\overline{\text{IN}}$
2, 7 17,24	GND		Negative Supply Voltage, Note 2
1, 8, 9, 16, 18, 23, 25, 32	V <sub>CC</sub>		Positive Supply Voltage, Note 2
31, 30, 29, 28, 27, 26, 22, 21, 20, 19, 15, 14, 13, 12, 11, 10	Q0, $\overline{\text{Q0}}$ , Q1, $\overline{\text{Q1}}$ , Q2, $\overline{\text{Q2}}$ , Q3, $\overline{\text{Q3}}$ , Q4, $\overline{\text{Q4}}$ , Q5, $\overline{\text{Q5}}$ , Q6, $\overline{\text{Q6}}$ , Q7, $\overline{\text{Q7}}$	CML	Non-inverted / Inverted Differential Output. Note 1
5	VREFAC		Output Voltage Reference for Capacitor-Coupled Inputs, only
-	EP	-	The Exposed Pad (EP) on the QFN-24 package bottom is thermally connected to the die for improved heat transfer out of package. The exposed pad must be attached to a heat-sinking conduit. The pad is electrically connected to GND and is recommended to be electrically connected to GND on the PC board.

1. In the differential configuration when the input termination pin ( $V_T$ ) is connected to a common termination voltage or left open, and if no signal is applied on IN/ $\overline{\text{IN}}$ , then the device will be susceptible to self-oscillation. Qn/ $\overline{\text{Qn}}$  outputs have internal 50  $\Omega$  source termination resistors.
2. All V<sub>CC</sub> and GND pins must be externally connected to the same power supply voltage to guarantee proper device operation.

# NB7L1008M

**Table 2. ATTRIBUTES**

Characteristics	Value
ESD Protection Human Body Model Machine Model	> 2 kV > 200 V
Moisture Sensitivity (Note 3) Indefinite Time of the Drypack QFN-32	Level 1
Flammability Rating Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in
Transistor Count	263
Meets or exceeds JEDEC Spec EIA/JESD78 IC Latchup Test	

3. For additional information, refer to Application Note AND8003/D.

**Table 3. MAXIMUM RATINGS**

Symbol	Parameter	Condition 1	Condition 2	Rating	Unit
V <sub>CC</sub>	Positive Power Supply	GND = 0 V		4.0	V
V <sub>IN</sub>	Input Voltage	GND = 0 V		-0.5 to V <sub>CC</sub>	V
V <sub>INPP</sub>	Differential Input Voltage  I <sub>N</sub> - I <sub>N</sub>			1.89	V
I <sub>IN</sub>	Input Current Through R <sub>T</sub> (50 Ω Resistor)			± 40	mA
I <sub>out</sub>	Output Current	Continuous Surge		34 40	mA
I <sub>VFREFAC</sub>	V <sub>REFAC</sub> Sink/Source Current			± 1.5	mA
T <sub>A</sub>	Operating Temperature Range			-40 to +85	°C
T <sub>stg</sub>	Storage Temperature Range			-65 to +150	°C
θ <sub>JA</sub>	Thermal Resistance (Junction-to-Ambient) (Note 4) TGSD 51-6 (2S2P Multilayer Test Board) with Filled Thermal Vias	0 lfpm 500 lfpm	QFN-32 QFN-32	31 27	°C/W °C/W
θ <sub>JC</sub>	Thermal Resistance (Junction-to-Case)	Standard Board	QFN-32	12	°C/W
T <sub>sol</sub>	Wave Solder Pb-Free			265	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

4. JEDEC standard multilayer board – 2S2P (2 signal, 2 power) with 8 filled thermal vias under exposed pad.

# NB7L1008M

**Table 4. DC CHARACTERISTICS – CML OUTPUT**  $V_{CC} = 2.375\text{ V to }3.6\text{ V}$ ;  $GND = 0\text{ V}$   $T_A = -40^\circ\text{C to }85^\circ\text{C}$  (Note 6)

Symbol	Characteristic	Min	Typ	Max	Unit
--------	----------------	-----	-----	-----	------

## POWER SUPPLY

$V_{CC}$	Power Supply Voltage	$V_{CC} = 3.3\text{ V}$ $V_{CC} = 2.5\text{ V}$	3.0 2.375	3.3 2.5	3.6 2.625	V
----------	----------------------	--	--------------	------------	--------------	---

## POWER SUPPLY CURRENT

$I_{CC}$	Power Supply Current, Inputs and Outputs Open			265	315	mA
----------	---	--	--	-----	-----	----

## CML OUTPUTS (Note 5, Figures 10 and 11)

$V_{OH}$	Output HIGH Voltage	$V_{CC} = 3.3\text{ V}$ $V_{CC} = 2.5\text{ V}$	$V_{CC} - 30$ 3270 2470	$V_{CC} - 10$ 3290 2490	$V_{CC}$ 3300 2500	mV
$V_{OL}$	Output LOW Voltage	$V_{CC} = 3.3\text{ V}$ $V_{CC} = 2.5\text{ V}$	$V_{CC} - 600$ 2700 1900	$V_{CC} - 400$ 2900 2100	$V_{CC} - 350$ 2950 2150	mV

## DIFFERENTIAL INPUTS DRIVEN SINGLE-ENDED (Notes 7 and 8) (Figures 6 and 8)

$V_{IH}$	Single-Ended Input HIGH Voltage		$V_{th} + 100$		$V_{CC}$	mV
$V_{IL}$	Single-Ended Input LOW Voltage		GND		$V_{th} - 100$	mV
$V_{th}$	Input Threshold Reference Voltage Range		1100		$V_{CC} - 100$	mV
$V_{ISE}$	Single-Ended Input Voltage ( $V_{IH} - V_{IL}$ )		200		1200	mV

## $V_{REFAC}$

$V_{REFAC}$	Output Reference Voltage @ 100 $\mu\text{A}$ for Capacitor – Coupled Inputs, Only	$V_{CC} = 3.3\text{ V}$ $V_{CC} = 2.5\text{ V}$	$V_{CC} - 1375$ $V_{CC} - 1325$	$V_{CC} - 1200$ $V_{CC} - 1200$	$V_{CC} - 1100$ $V_{CC} - 1075$	mV
-------------	---	--	------------------------------------	------------------------------------	------------------------------------	----

## DIFFERENTIAL INPUTS DRIVEN DIFFERENTIALLY ( $I_N$ , $\bar{I}_N$ ) (Note 9) (Figures 4 and 7)

$V_{IHD}$	Differential Input HIGH Voltage		1100		$V_{CC}$	mV
$V_{ILD}$	Differential Input LOW Voltage		GND		$V_{IHD} - 100$	mV
$V_{ID}$	Differential Input Voltage ( $V_{IHD} - V_{ILD}$ )		100		1200	mV
$I_{IH}$	Input HIGH Current		-150	40	+150	$\mu\text{A}$
$I_{IL}$	Input LOW Current		-150	5	+150	$\mu\text{A}$

## TERMINATION RESISTORS

$R_{TIN}$	Internal Input Termination Resistor		45	50	55	$\Omega$
$R_{TOUT}$	Internal Output Termination Resistor		45	50	55	$\Omega$

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

- CML outputs loaded with 50  $\Omega$  to  $V_{CC}$  for proper operation.
- Input and output parameters vary 1:1 with  $V_{CC}$ .
- $V_{th}$ ,  $V_{IH}$ ,  $V_{IL}$ , and  $V_{ISE}$  parameters must be complied with simultaneously.
- $V_{th}$  is applied to the complementary input when operating in single-ended mode.
- $V_{IHD}$ ,  $V_{ILD}$ ,  $V_{ID}$  and  $V_{CMR}$  parameters must be complied with simultaneously.

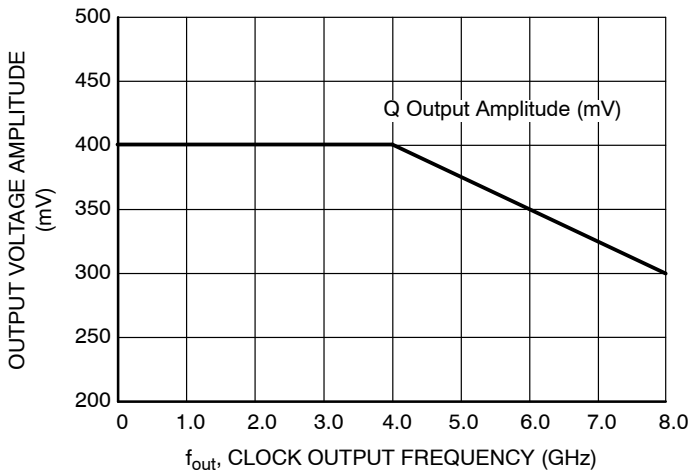
# NB7L1008M

**Table 5. AC CHARACTERISTICS**  $V_{CC} = 2.375\text{ V to }3.6\text{ V}$ ;  $GND = 0\text{ V}$   $T_A = -40^\circ\text{C to }85^\circ\text{C}$  (Note 10)

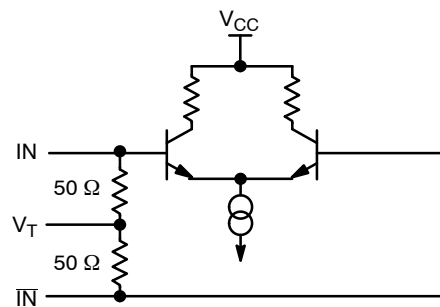
Symbol	Characteristic	Min	Typ	Max	Unit
$f_{\text{DATA}}$	Maximum Operating Input Data Rate	10	12		Gb/s
$f_{\text{INCLK}}$	Maximum Input Clock Frequency, $V_{\text{OUTPP}} \geq 200\text{ mV}$	6	8		GHz
$V_{\text{OUTPP}}$	Output Voltage Amplitude (see Figures 2 and 5, Note 11) $f_{\text{in}} \leq 4\text{ GHz}$ $f_{\text{in}} \leq 6\text{ GHz}$	200 200	400 350		mV
$V_{\text{CMR}}$	Input Common Mode Range (Differential Configuration, Note 12, Figure 9)	1050		$V_{\text{CC}} - 50$	mV
$t_{\text{PLH}}, t_{\text{PHL}}$	Propagation Delay to Output Differential, $\text{IN}/\overline{\text{IN}}$ to $\text{Qn}/\overline{\text{Qn}}$	100	160	250	ps
$t_{\text{PLH TC}}$	Propagation Delay Temperature Coefficient $-40^\circ\text{C to }+85^\circ\text{C}$		35		fs/ $^\circ\text{C}$
$t_{\text{DC}}$	Output Clock Duty Cycle $f_{\text{in}} \leq 6\text{ GHz}$	45	49/51	55	%
$t_{\text{SKEW}}$	Duty Cycle Skew (Note 13) Within Device Skew (Note 14) Device to Device Skew (Note 15)		0.15 7 25	1 25 70	ps
$t_{\text{JITTER}}$	Clock Jitter RMS, 1000 Cycles (Note 16) $f_{\text{in}} \leq 6\text{ GHz}$ Data Dependent Jitter (DDJ) (Note 17) $\leq 10\text{ Gb/s}$		0.2 3	0.8 20	ps
$V_{\text{INPP}}$	Input Voltage Swing (Differential Configuration) (Note 18) (Figure 5)	100		1200	mV
$t_{\text{r}}, t_{\text{f}}$	Output Rise/Fall Times (20% – 80%) $\text{Qn}, \overline{\text{Qn}}$	20	45	70	ps

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

10. Measured using a 400 mV source, 50% duty cycle 1 GHz clock source. All outputs must be loaded with external  $50\ \Omega$  to  $V_{\text{CC}}$ . Input edge rates 40 ps (20% – 80%).
11. Output voltage swing is a single-ended measurement operating in differential mode.
12.  $V_{\text{CMR}}$  min varies 1:1 with GND,  $V_{\text{IHCMR}}$  max varies 1:1 with  $V_{\text{CC}}$ . The  $V_{\text{IHCMR}}$  range is referenced to the most positive side of the differential input signal.
13. Duty cycle skew is measured between differential outputs using the deviations of the sum of  $T_{\text{pw-}}$  and  $T_{\text{pw+}}$  @ 1 GHz.
14. Within device skew compares coincident edges.
15. Device to device skew is measured between outputs under identical transition
16. Additive CLOCK jitter with 50% duty cycle clock signal.
17. Additive Peak-to-Peak jitter with input NRZ data at PRBS23.
18. Input voltage swing is a single-ended measurement operating in differential mode.



**Figure 2. Output Voltage Amplitude ( $V_{\text{OUTPP}}$ ) vs. Input Frequency ( $f_{\text{in}}$ ) at Ambient Temperature (Typical)**



**Figure 3. Input Structure**

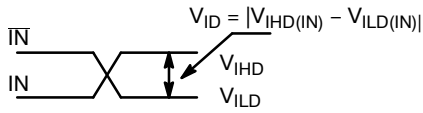


Figure 4. Differential Inputs Driven Differentially

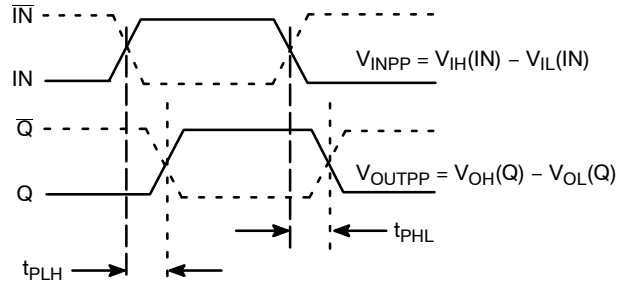


Figure 5. AC Reference Measurement

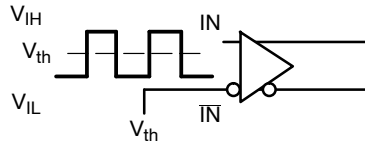


Figure 6. Differential Input Driven Single-Ended

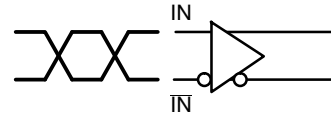


Figure 7. Differential Inputs Driven Differentially

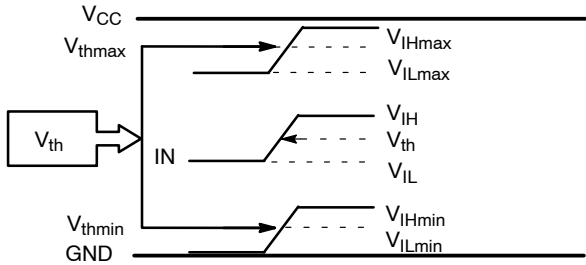


Figure 8.  $V_{th}$  Diagram

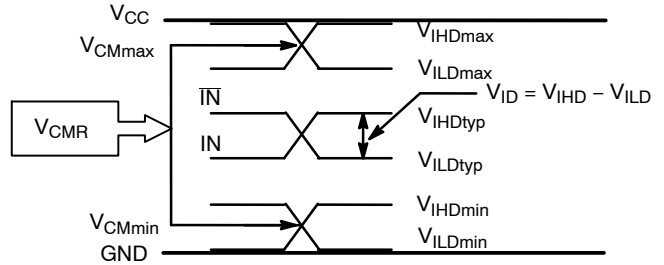
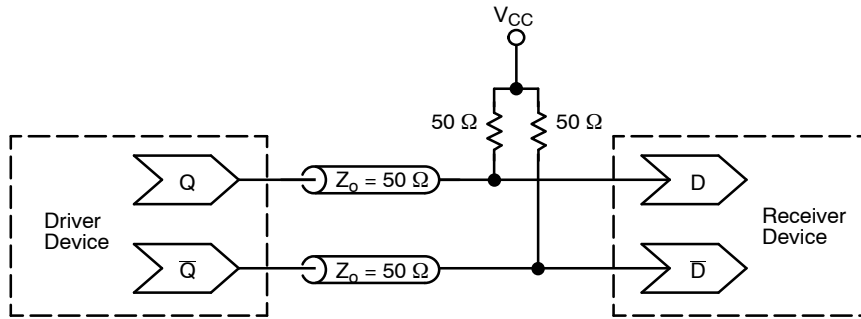
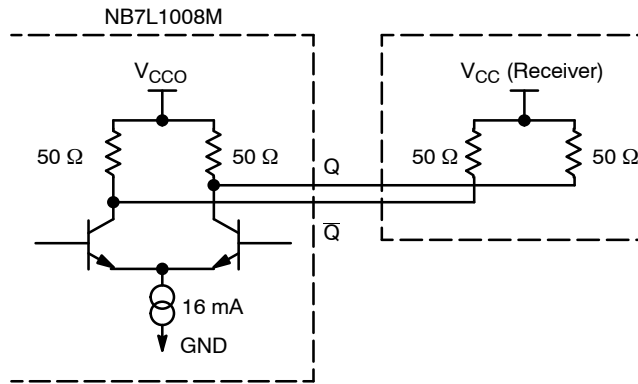


Figure 9.  $V_{CM}$  Diagram

# NB7L1008M



**Figure 10. Typical Termination for Output Driver and Device Evaluation**  
(See Application Note AND8173/D)



**Figure 11. Typical CML Output Structure and Termination**

# NB7L1008M

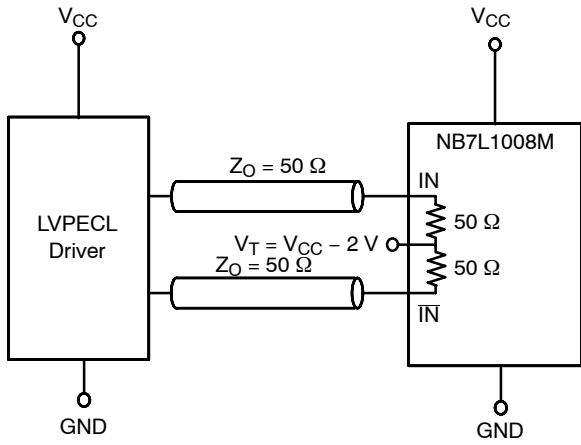


Figure 12. LVPECL Interface

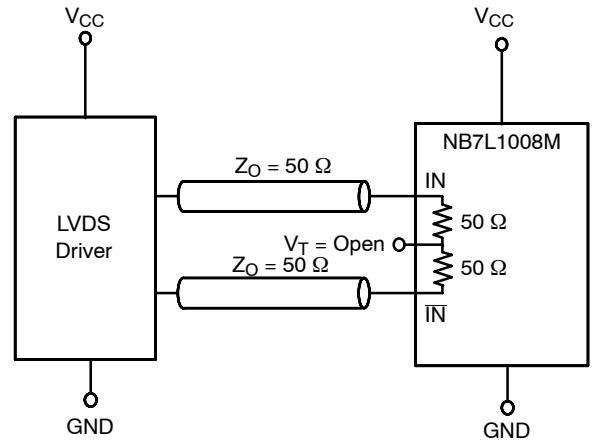


Figure 13. LVDS Interface

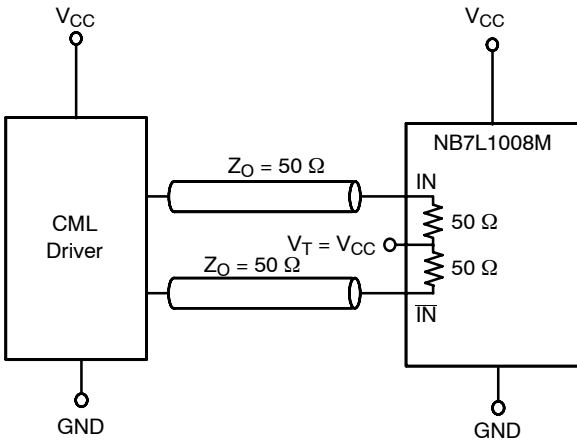


Figure 14. Standard 50 Ω Load CML Interface

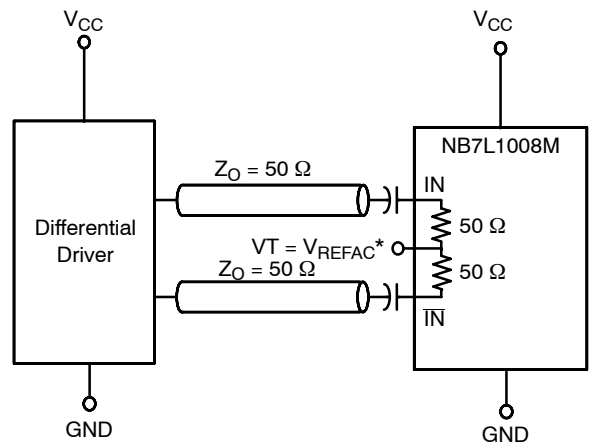


Figure 15. Capacitor-Coupled Differential Interface  
( $V_T$  Connected to  $V_{REFFAC}$ )

\* $V_{REFFAC}$  bypassed to ground with a 0.01  $\mu\text{F}$  capacitor

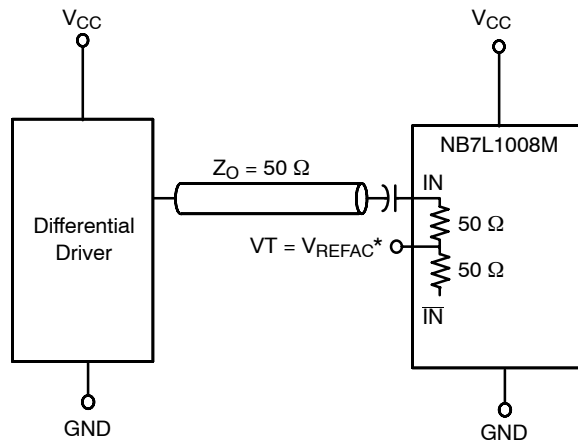


Figure 16. Capacitor-Coupled Single-Ended Interface  
( $V_T$  Connected to  $V_{REFFAC}$ )



# NB7L1008M

## ORDERING INFORMATION

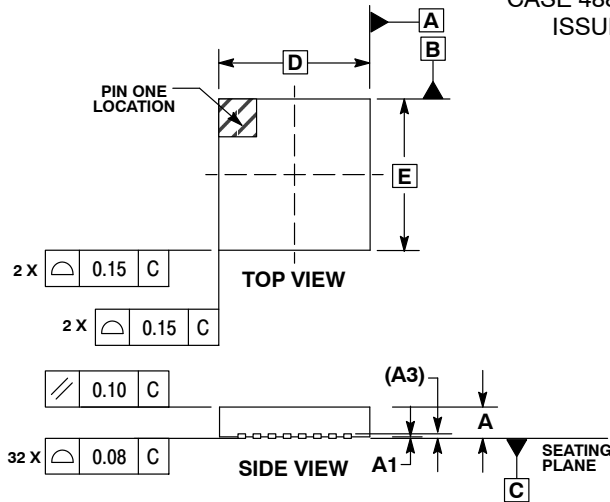
Device	Package	Shipping
NB7L1008MMNG	QFN32 (Pb-Free)	74 Units / Rail
NB7L1008MMNR4G	QFN32 (Pb-Free)	1000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# NB7L1008M

## PACKAGE DIMENSIONS

QFN32 5\*5\*1 0.5 P  
CASE 488AM-01  
ISSUE O

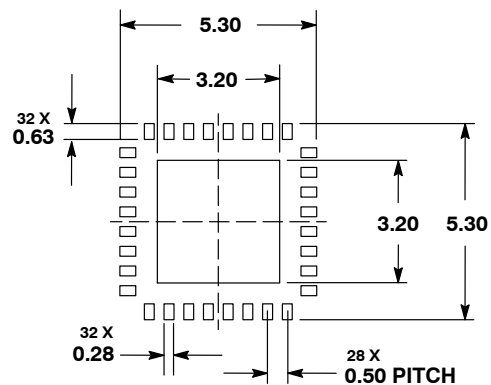


**NOTES:**

1. DIMENSIONS AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30 MM TERMINAL
4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

DIM	MILLIMETERS		
	MIN	NOM	MAX
A	0.800	0.900	1.000
A1	0.000	0.025	0.050
A3	0.200 REF		
b	0.180	0.250	0.300
D	5.00 BSC		
D2	2.950	3.100	3.250
E	5.00 BSC		
E2	2.950	3.100	3.250
e	0.500 BSC		
K	0.200	---	---
L	0.300	0.400	0.500

### SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GigaComm is a trademark of Semiconductor Components Industries, LLC (SCILLC).

ON Semiconductor and are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

### PUBLICATION ORDERING INFORMATION

**LITERATURE FULFILLMENT:**  
Literature Distribution Center for ON Semiconductor  
P.O. Box 5163, Denver, Colorado 80217 USA  
**Phone:** 303-675-2175 or 800-344-3860 Toll Free USA/Canada  
**Fax:** 303-675-2176 or 800-344-3867 Toll Free USA/Canada  
**Email:** orderlit@onsemi.com

**N. American Technical Support:** 800-282-9855 Toll Free USA/Canada  
**Europe, Middle East and Africa Technical Support:**  
Phone: 421 33 790 2910  
**Japan Customer Focus Center**  
Phone: 81-3-5773-3850

**ON Semiconductor Website:** [www.onsemi.com](http://www.onsemi.com)  
**Order Literature:** <http://www.onsemi.com/orderlit>  
For additional information, please contact your local Sales Representative



## Стандарт Электрон Связь

Мы молодая и активно развивающаяся компания в области поставок электронных компонентов. Мы поставляем электронные компоненты отечественного и импортного производства напрямую от производителей и с крупнейших складов мира.

Благодаря сотрудничеству с мировыми поставщиками мы осуществляем комплексные и плановые поставки широчайшего спектра электронных компонентов.

Собственная эффективная логистика и склад в обеспечивает надежную поставку продукции в точно указанные сроки по всей России.

Мы осуществляем техническую поддержку нашим клиентам и предпродажную проверку качества продукции. На все поставляемые продукты мы предоставляем гарантию .

Осуществляем поставки продукции под контролем ВП МО РФ на предприятия военно-промышленного комплекса России , а также работаем в рамках 275 ФЗ с открытием отдельных счетов в уполномоченном банке. Система менеджмента качества компании соответствует требованиям ГОСТ ISO 9001.

Минимальные сроки поставки, гибкие цены, неограниченный ассортимент и индивидуальный подход к клиентам являются основой для выстраивания долгосрочного и эффективного сотрудничества с предприятиями радиоэлектронной промышленности, предприятиями ВПК и научно-исследовательскими институтами России.

С нами вы становитесь еще успешнее!

### Наши контакты:

**Телефон:** +7 812 627 14 35

**Электронная почта:** [sales@st-electron.ru](mailto:sales@st-electron.ru)

**Адрес:** 198099, Санкт-Петербург,  
Промышленная ул, дом № 19, литера Н,  
помещение 100-Н Офис 331